

# OM SENI

## MBRS120T3G, MBRS130T3G, MBRS140T3G, MBRS190T3G, MBRS1100T3G Schottky Power Rectifier

### Surface Mount Power Package

Schottky Power Rectifiers employ the use of the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system. These state-of-the-art devices have the following features:

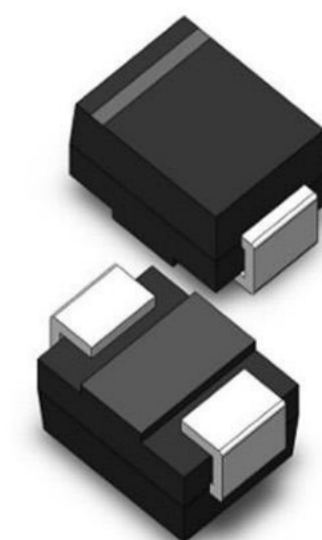
#### Features

- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- High Blocking Voltage – 100 Volts
- 175°C Operating Junction Temperature
- Guardring for Stress Protection
- SBRS8 Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- All Packages are Pb-Free

#### Mechanical Characteristics

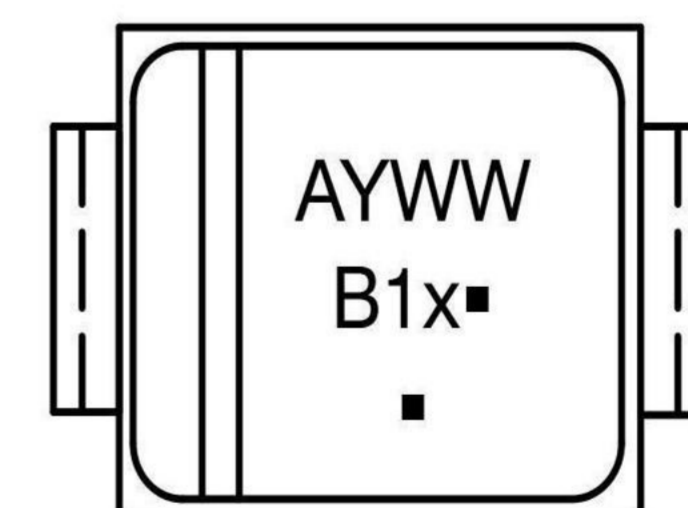
- Case: Epoxy, Molded
- Weight: 95 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 12 mm Tape and Reel, 2,500 units per reel
- Cathode Polarity Band

**SCHOTTKY BARRIER  
RECTIFIER  
1.0 AMPERE  
20-100 VOLTS**



**SMB  
CASE 403A**

#### MARKING DIAGRAM



- B1 = Device Code  
 x = C for MBRS1100T3  
     9 for MBRS190T3  
 A = Assembly Location  
 Y = Year  
 WW = Work Week  
 ■ = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

# OM SENI

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage MBRS190T3 MBRS1100T3	$V_{RRM}$ $V_{RWM}$ $V_R$	90 100	V
Average Rectified Forward Current $T_L = 163^\circ\text{C}$ $T_L = 148^\circ\text{C}$	$I_{F(AV)}$	1.0 2.0	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	$I_{FSM}$	50	A
Operating Junction Temperature (Note 1)	$T_J$	-65 to +175	$^\circ\text{C}$
Voltage Rate of Change	dv/dt	10	V/ns

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance - Junction-to-Lead ( $T_L = 25^\circ\text{C}$ )	$R_{\theta JL}$	22	$^\circ\text{C}/\text{W}$

## ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 2) ( $i_F = 1.0\text{ A}$ , $T_J = 25^\circ\text{C}$ )	$V_F$	0.75	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_J = 25^\circ\text{C}$ ) (Rated dc Voltage, $T_J = 100^\circ\text{C}$ )	$I_R$	0.5 5.0	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

## ORDERING INFORMATION

Device	Marking	Package	Shipping <sup>†</sup>
MBRS120T3G	B12	SMB (Pb-Free)	2500 / Tape & Reel
MBRS130T3G	B13	SMB (Pb-Free)	2500 / Tape & Reel
MBRS140T3G	B14	SMB (Pb-Free)	2500 / Tape & Reel
MBRS190T3G	B19	SMB (Pb-Free)	2500 / Tape & Reel
MBRS1100T3G	B1C	SMB (Pb-Free)	2500 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# OM SENI

## TYPICAL ELECTRICAL CHARACTERISTICS

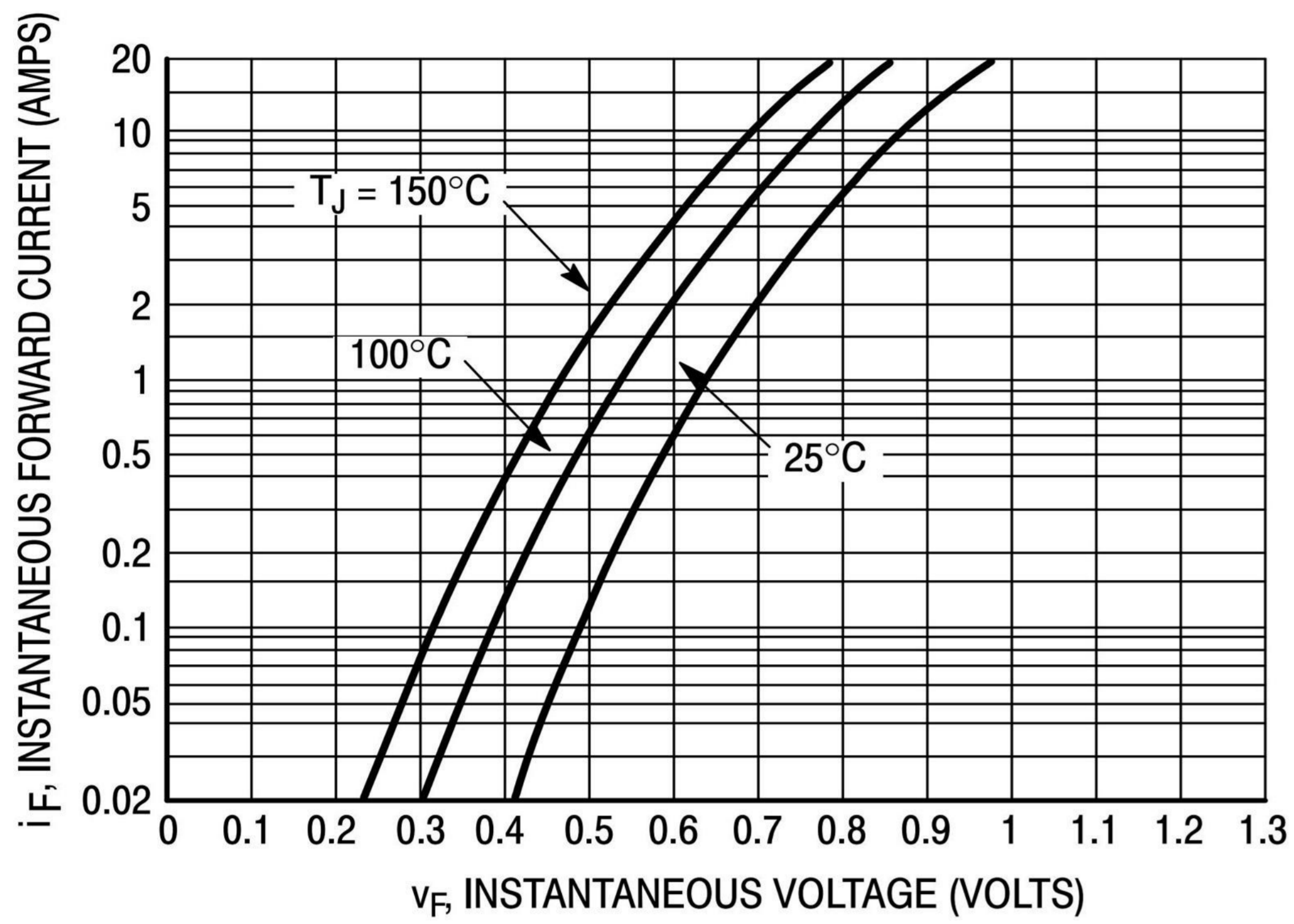


Figure 1. Typical Forward Voltage

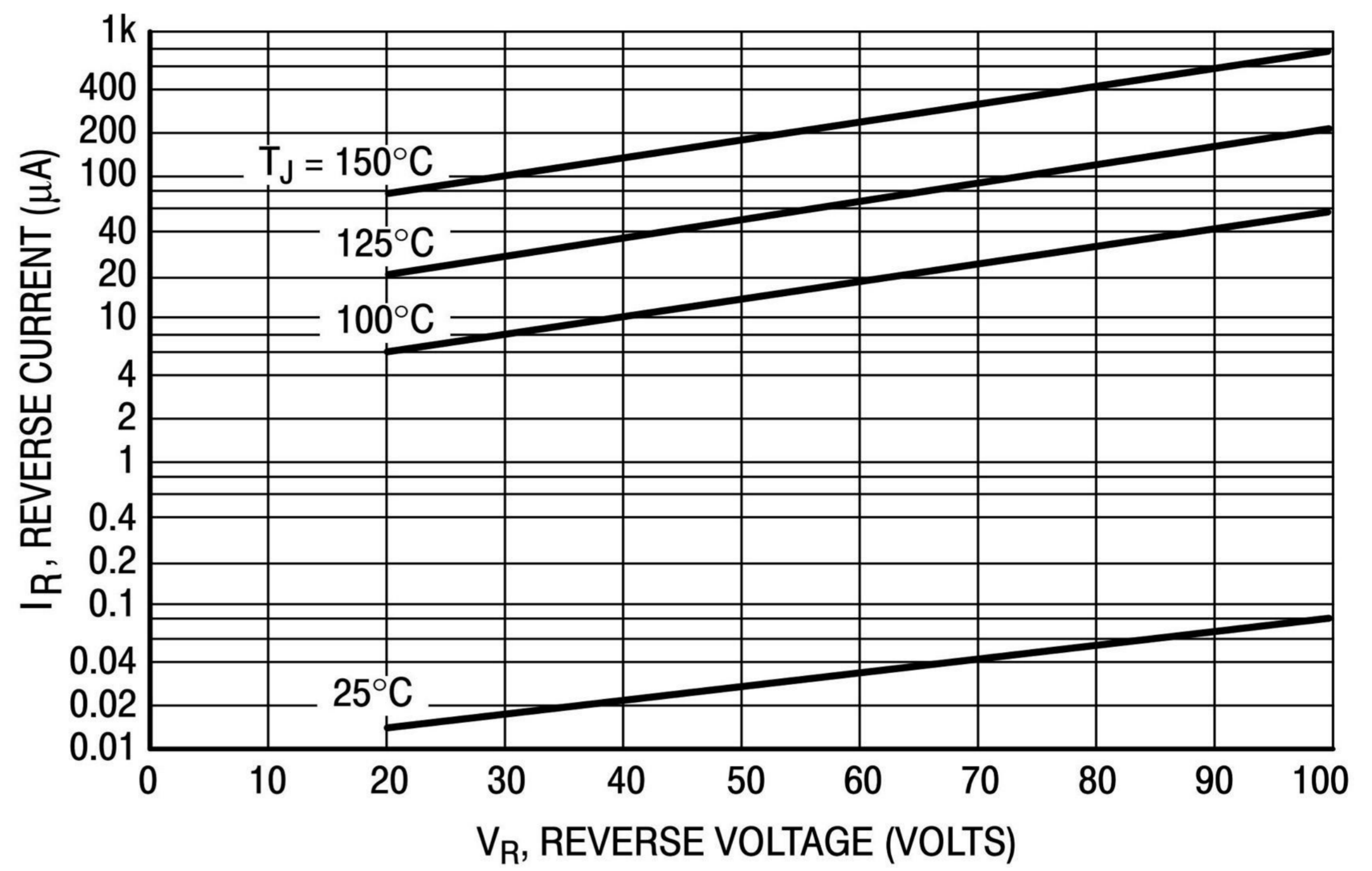


Figure 2. Typical Reverse Current\*

\*The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these curves if  $V_R$  is sufficient below rated  $V_R$ .

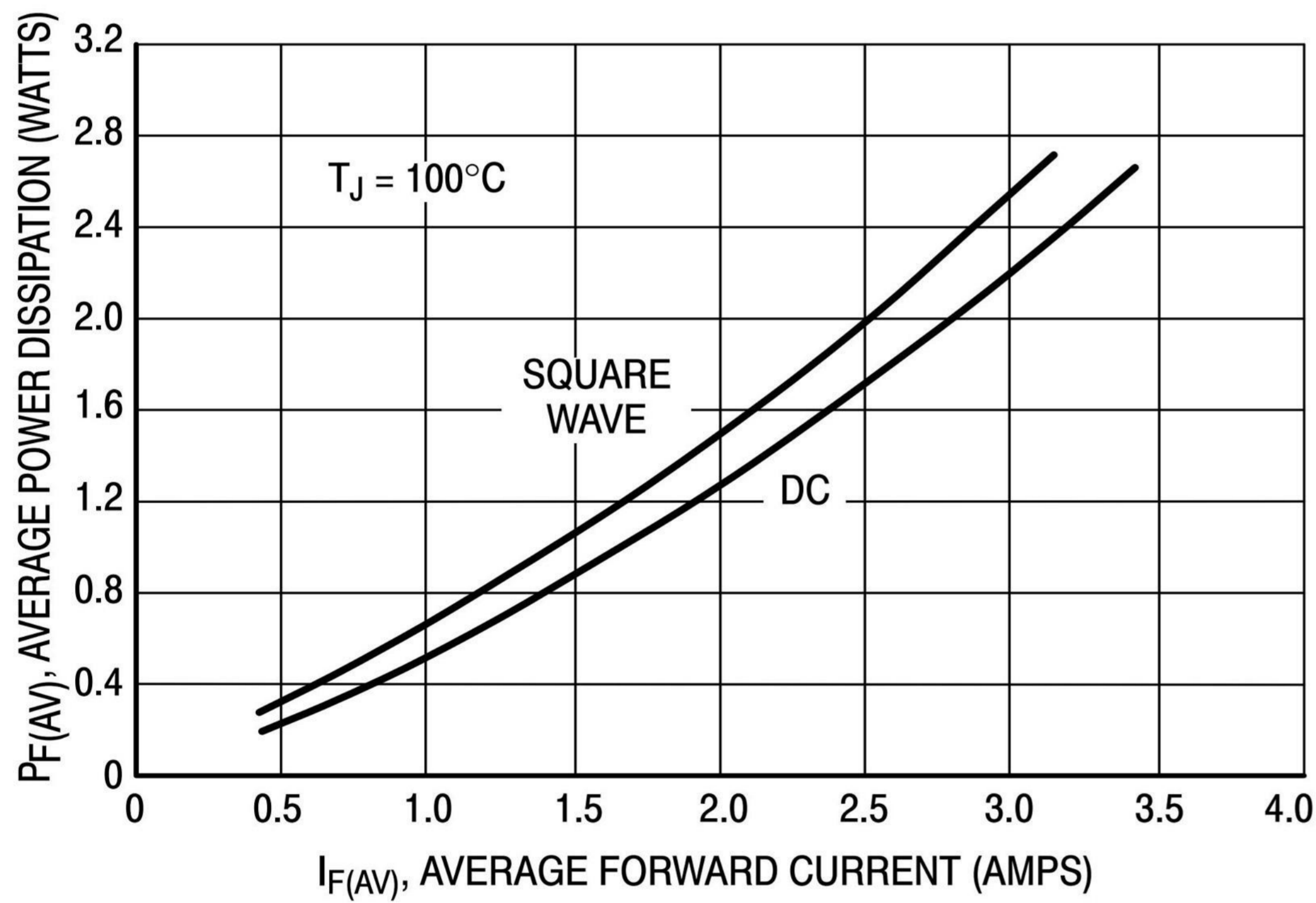


Figure 3. Power Dissipation

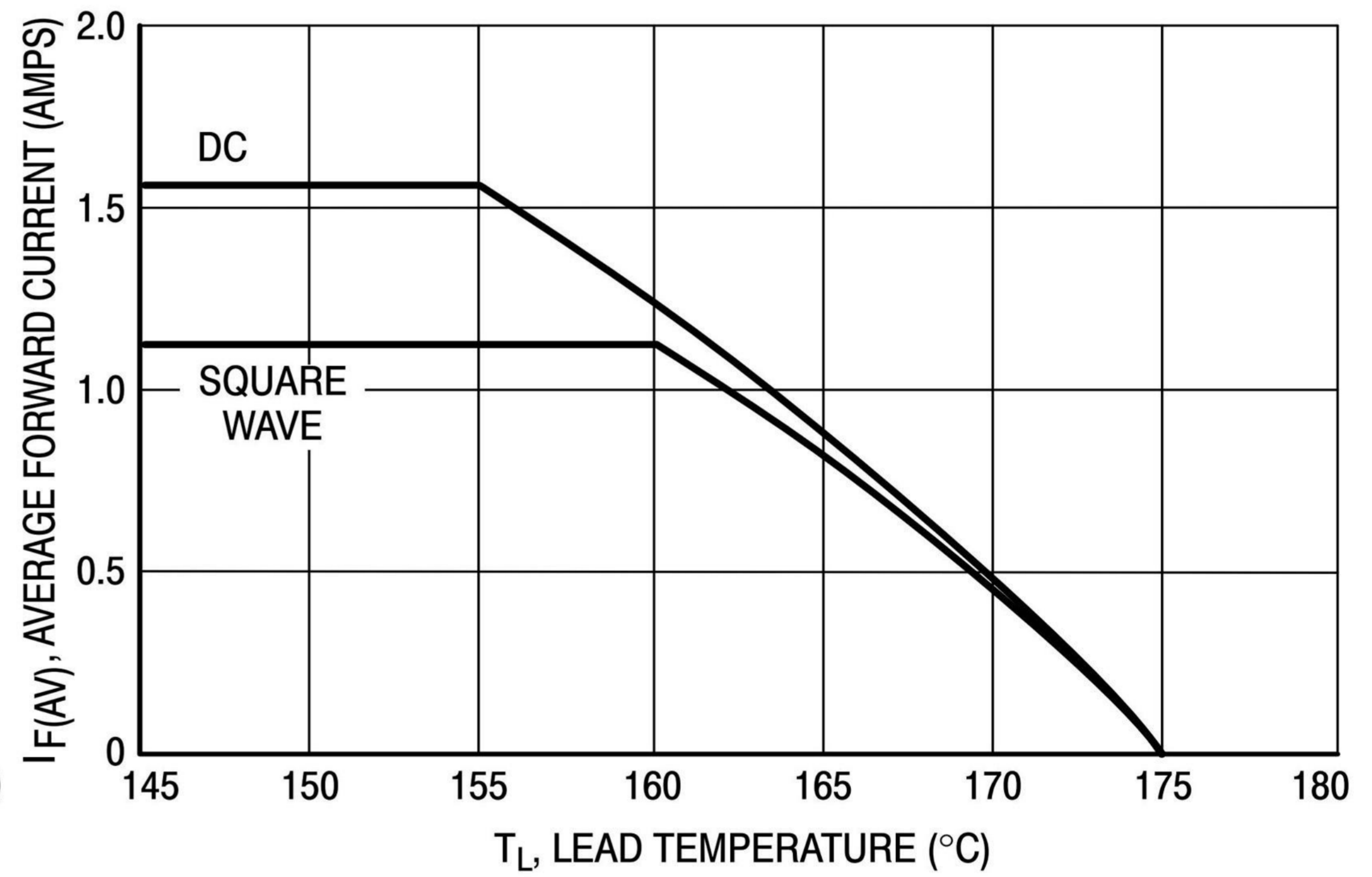


Figure 4. Current Derating, Lead

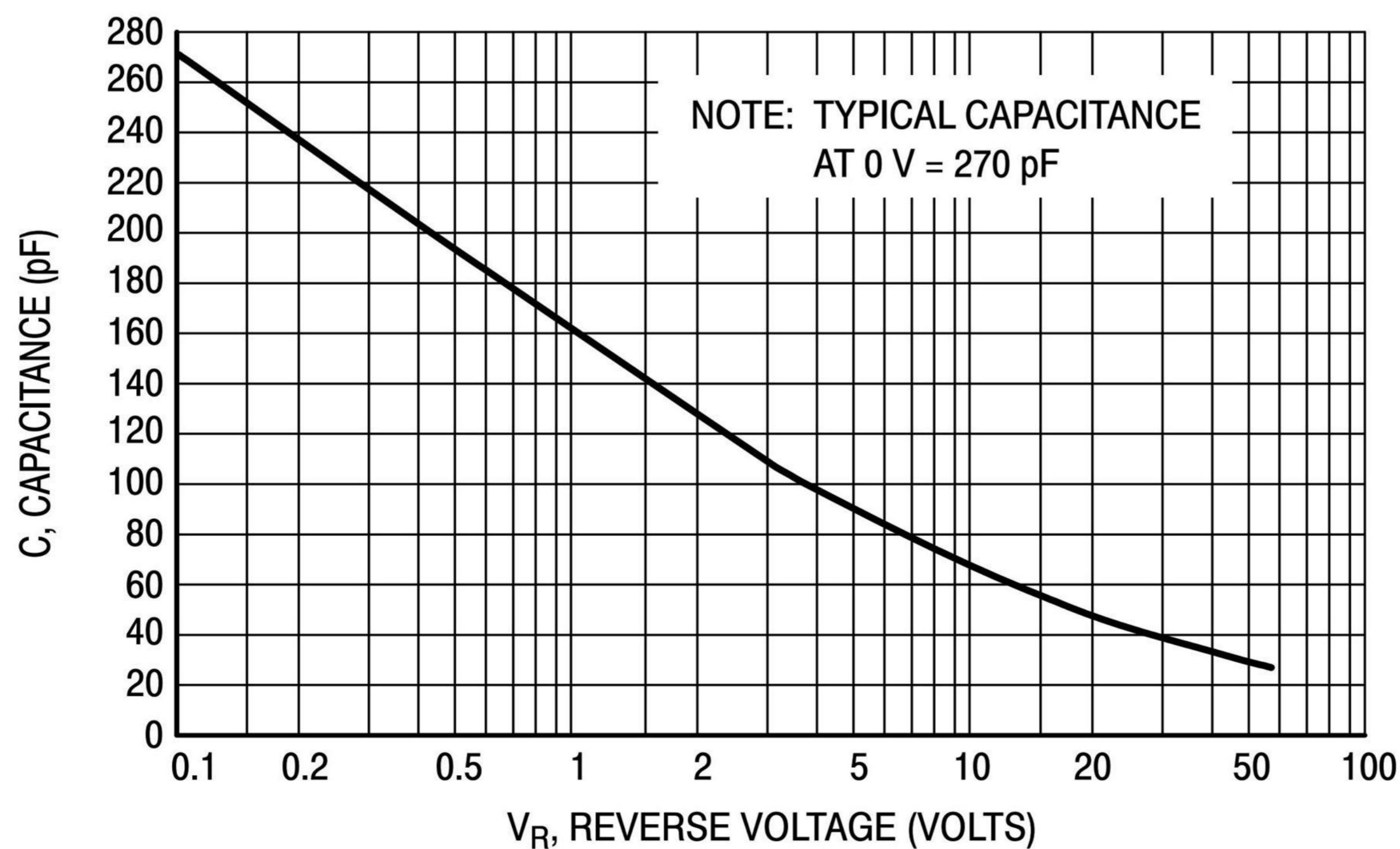


Figure 5. Typical Capacitance

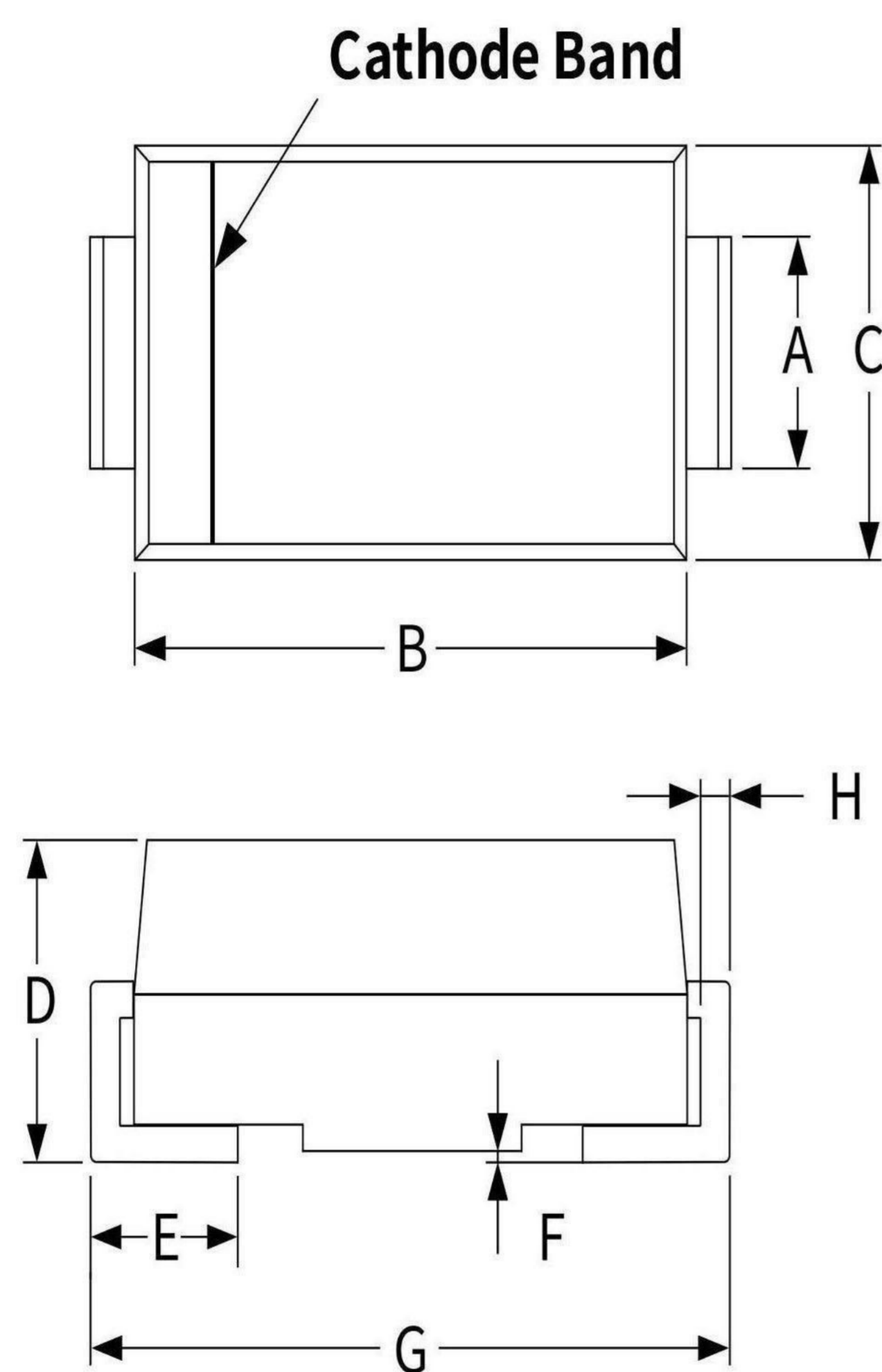
# OM SENI

## Ordering Information

PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SMB	R3	0.098	2500	5000	25000	13

## Package Outline Dimensions (SMB/DO-214AA)

Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	1.85	2.21	0.073	0.087
B	4.25	4.85	0.167	0.191
C	3.30	3.94	0.130	0.155
D	2.15	2.65	0.085	0.104
E	0.75	1.52	0.030	0.060
F	-	0.203	-	0.008
G	5.08	5.59	0.200	0.220
H	0.15	0.31	0.006	0.012



## Suggested Pad Layout

Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
M	2.26	-	0.089	-
J	2.10	-	0.085	-
K	-	2.74	-	0.107

